

# MMBT4126-7-F Datasheet



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DiGi Electronics Part Number MMBT4126-7-F-DG

Manufacturer Diodes Incorporated

Manufacturer Product Number MMBT4126-7-F

Description TRANS PNP 25V 0.2A SOT23-3

Detailed Description Bipolar (BJT) Transistor PNP 25 V 200 mA 250MHz 3

00 mW Surface Mount SOT-23-3



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# **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
MMBT4126-7-F	Diodes Incorporated
Series:	Product Status:
	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
PNP	200 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
25 V	400mV @ 5mA, 50mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
50nA (ICBO)	120 @ 2mA, 1V
Power - Max:	Frequency - Transition:
300 mW	250MHz
Operating Temperature:	Grade:
-55°C ~ 150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q101	Surface Mount
Package / Case:	Supplier Device Package:
TO-236-3, SC-59, SOT-23-3	SOT-23-3
Base Product Number:	
MMBT4126	

# **Environmental & Export classification**

8541.21.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

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PART OBSOLETE - USE MMBT3906-7-F



**MMBT4126** 

#### 25V PNP SMALL SIGNAL TRANSISTOR IN SOT23

#### **Features**

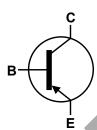
- Epitaxial Planar Die Construction
- Ideal for Medium Power Amplification and Switching
- Complementary NPN Type: MMBT4124
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

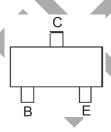
- Case: SOT23
- Case Material: Molded plastic, "Green" Molding Compound;
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (Approximate)







Device Symbol



Top View Pin-Out

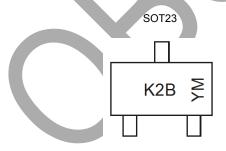
#### Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
MMBT4126-7-F	Standard	K2B	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**



K2B = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: D = 2016) M or  $\overline{M}$  = Month (ex: 9 = September)

#### Date Code Key

Year	2016	20	017	2018	2	2019	2020		2021	2022		2023
Code	D		E	F		G	Н			J		K
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



### Absolute Maximum Ratings (@TA = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-25	V
Collector-Emitter Voltage	$V_{CEO}$	-25	V
Emitter-Base Voltage	$V_{EBO}$	-4.0	V
Collector Current	I <sub>C</sub>	-200	mA

#### Thermal Characteristics (@TA = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	$P_D$	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	$R_{ heta JA}$	625	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

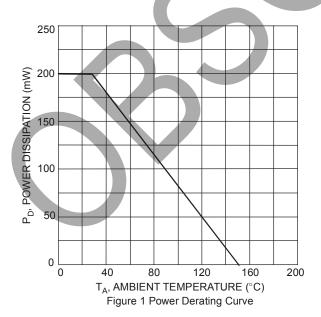
#### ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For the device mounted on minimum recommended pad layout FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

## **Thermal Characteristics and Derating Information**





### Electrical Characteristics (@T<sub>A</sub> = +25°C unless otherwise specified.)

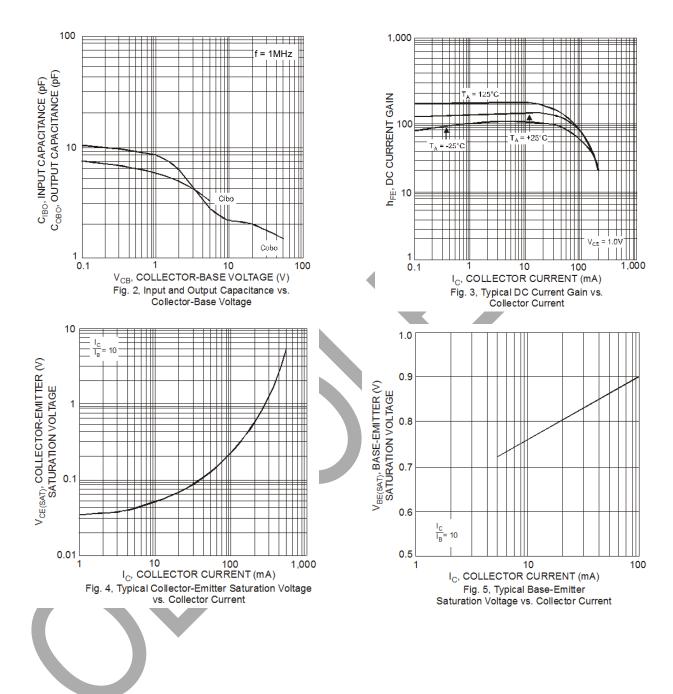
Characteristic	Comple of	Min	T	Max	I I m i A	Took Condition
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS			1			
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-25	_	_	V	$I_C = -10\mu A$ , $I_B = 0$
Collector-Emitter Breakdown Voltage (Note 7)	BV <sub>CEO</sub>	-25		_	V	$I_C = -10 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	-4.0	-	_	V	$I_E = -10\mu A, I_C = 0$
Collector Cut-Off Current	I <sub>CBO</sub>	-	_	-50	nA	$V_{CB} = -20V, I_{E} = 0$
Collector Cut-Off Current	I <sub>EBO</sub>	-	-	-50	nA	$V_{EB} = -3.0V, I_{C} = 0$
ON CHARACTERISTICS (Note 7)						
DC Current Gain	h <sub>FE</sub>	120	_	360		$I_C = -2.0$ mA, $V_{CE} = -1.0$ V
DC Current Gain		60	_	_		$I_C = -50 \text{mA}, V_{CE} = -1.0 \text{V}$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>			-0.4	٧	$I_C = -50 \text{mA}, I_B = -5.0 \text{mA}$
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	-	-	-0.95	V	$I_C = -50 \text{mA}, I_B = 5.0 \text{mA}$
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C <sub>OBO</sub>			4.5	pF	$V_{CB} = -5.0V$ , $f = 1.0MHz$ , $I_E = 0$
Input Capacitance	C <sub>IBO</sub>			10	рF	$V_{EB} = -0.5V$ , $f = 1.0MHz$ , $I_C = 0$
Small Signal Current Gain	h <sub>FE</sub>	120	ı	480	1	$V_{CE} = -1.0V$ , $I_{C} = -2.0$ mA, $f = 1.0$ kHz
Current Gain Bandwidth Product	f <sub>T</sub>	250	_	_	MHz	$V_{CE} = -20V$ , $I_{C} = -10mA$ , $f = 100MHz$
Noise Figure	NF		/-	4.0	dB	$V_{CE}$ = -5.0V, $I_{C}$ = -100 $\mu$ A, $R_{S}$ = 1.0k $\Omega$ , $f$ = 1.0kHz

Note: 7. Short duration pulse test used to minimize self-heating effect.





### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

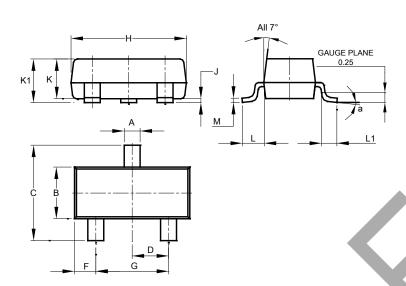




### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

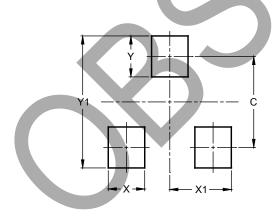


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
C	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Η	2.80	3.00	2.90				
7	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
٦	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All Dimensions in mm							

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
X	0.8
X1	1.35
Y	0.9
1/4	0.0



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